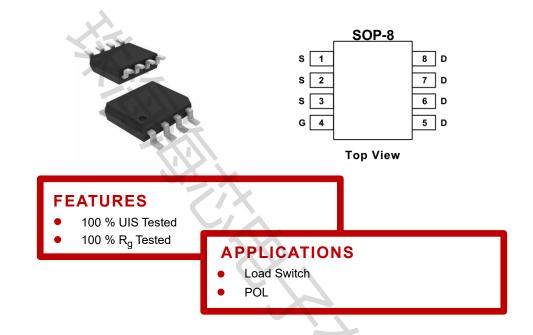
## SI4401DDY-T1-GE3-HX P-Channel 40-V(D-S) MOSFET

PRODUCT SUMMARY						
VDS (V)	RDS(on) (Ω)	Qg (Typ.)	ID (A)			
-40	0.010 at Vgs = - 10 V	2220	-16.1			
	0.014 at Vgs = - 4.5 V	33nC	-13.3			



Absolute Maximum Ratings							
	Parameter	Max.	Units				
V <sub>DS</sub>	Drain- Source Voltage	-40	V				
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ -10V	-10.5					
I <sub>D</sub> @ T <sub>A</sub> = 70°C	Continuous Drain Current, V <sub>GS</sub> @ -10V	-8.6	А				
I <sub>DM</sub>	Pulsed Drain Current ①	-43					
P <sub>D</sub> @T <sub>A</sub> = 25°C	Power Dissipation ③	2.5	W				
P <sub>D</sub> @T <sub>A</sub> = 70°C	Power Dissipation ③	1.6					
	Linear Derating Factor	20	mW/°C				
V <sub>GS</sub>	Gate-to-Source Voltage	± 20	V				
T <sub>J,</sub> T <sub>STG</sub>	Junction and Storage Temperature Range	-55 to + 150	°C				

Thermal Resistance						
	Parameter	Max.	Units			
R <sub>θ</sub> JA	Maximum Junction-to-Ambient③	50	°C/W			

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Electrical Characteristics @ TJ = 25° C (unless otherwise specified)						
	Parameter	Min.	Тур.	Max.	Units	Conditions
V <sub>(BR)DSS</sub>	Drain-to-Source Breakdown Voltage	-40			V	$V_{GS} = 0V, I_D = -250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		-0.025		V/°C	Reference to 25°C, I <sub>D</sub> = -1mA
R <sub>DS(on)</sub>				0.015	Ω	$V_{GS}$ = -10V, $I_{D}$ = -10.5A ②
29(0)	Static Drain-to-Source On-Resistance			0.025		$V_{GS}$ = -4.5V, $I_{D}$ = -8.4A ②
V <sub>GS(th)</sub>	Gate Threshold Voltage	-1.0		-3.0	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
gfs	Forward Transconductance	17			S	$V_{DS} = -10V, I_{D} = -10.5A$
I <sub>DSS</sub>	Drain-to-Source Leakage Current			-15	μA	$V_{DS} = -32V, V_{GS} = 0V$
500				-25	μπ	$V_{DS} = -32V, V_{GS} = 0V, T_{J} = 70^{\circ}C$
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			-100	nA	V <sub>GS</sub> = -20V
000	Gate-to-Source Reverse Leakage			100		V <sub>GS</sub> = 20V
Qg	Total Gate Charge		73	110		ID=-10.5A
Q <sub>gs</sub>	Gate-to-Source Charge		31	47	nC	VDS= -20V
Q <sub>gd</sub>	Gate-to-Drain ("Miller") Charge	X	17	26		VGS = -10V
t <sub>d(on)</sub>	Turn-On Delay Time		52			V <sub>DD</sub> = -20V ②
t <sub>r</sub>	Rise Time		490		ns	$I_D = -1.0A$
t <sub>d(off)</sub>	Turn-Off Delay Time		210		113	$R_G = 6.0\Omega$
t <sub>f</sub>	Fall Time		97	云		V <sub>GS</sub> = -10V
C <sub>iss</sub>	Input Capacitance		9250			VGS=0V
Coss	Output Capacitance		580		pF	VDS= -25V
C <sub>rss</sub>	Reverse Transfer Capacitance		520			f = 1.0kHz

Sc	Source-Drain Ratings and Characteristics						
	Parameter	Min.	Тур.	Max.	Units	Conditions	
Is	Continuous Source Current(Body Diode)			-2.5	A		
I <sub>SM</sub>	Pulsed Source Current(Body Diode) ①			-43	, ,		
V <sub>SD</sub>	Diode Forward Voltage			-1.2	V	$T_J = 25^{\circ}C$ , $I_S = -2.5A$ , $V_{GS} = 0V$ 2	
t <sub>rr</sub>	Reverse Recovery Time		43	65	ns	T <sub>J</sub> = 25°C, I <sub>F</sub> = -2.5A	
$Q_{rr}$	Reverse Recovery Charge		75	110	nC	di/dt = -100A/µs ②	

### Notes:

- ①Repetitive rating; pulse width limited by max. junction temperature.
- ②Pulse width  $\leq$  400 $\mu$ s; duty cycle  $\leq$  2%.
- ③Surface mounted on 1 in square Cu board, t ≤ 5sec.

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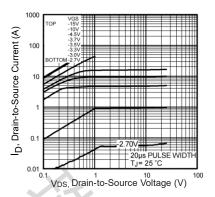


Fig 1. Typical Output Characteristics

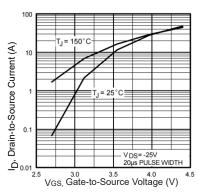


Fig 2. Typical Transfer Characteristics

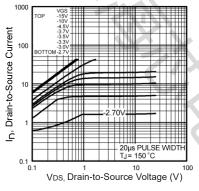


Fig 3. Typical Output

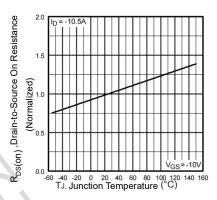


Fig 4. Normalized On-Resistance Vs. Temperature

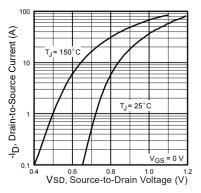


Fig 5. Typical Source-Drain Diode Forward Voltage

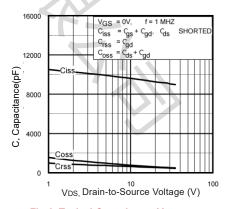


Fig 6. Typical Capacitance Vs.
Drain-to-Source Voltage

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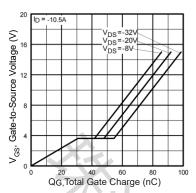


Fig 7. Typical Gate Charge Vs.
Gate-to-Source Voltage

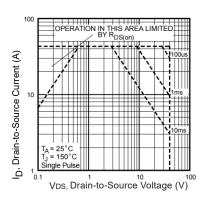


Fig 8.Maximum Safe Operating Area

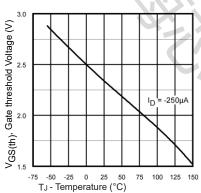


Fig 9. Typical Vgs(th) Vs.

Junction Temperature

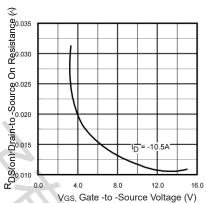


Fig 10. Typical On-Resistance Vs.
Gate Voltage

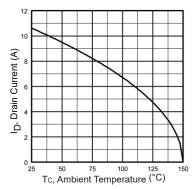


Fig 11. Maximum Drain Current Vs.

Case Temperature

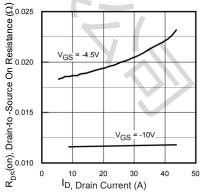


Fig 12. Typical On-Resistance Vs.

Drain Current

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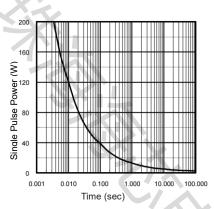


Fig 13. Typical Power Vs. Time

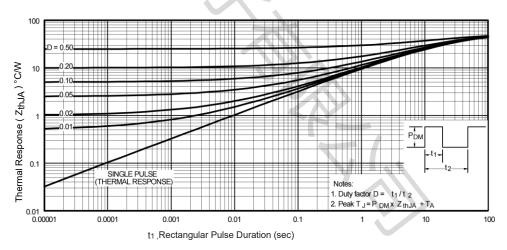
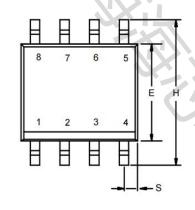


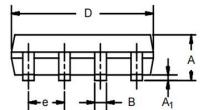
Fig 14. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

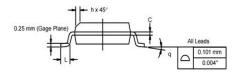
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# **SOP-8 Package Outline**

Dimensions are shown in millimeters (inches)



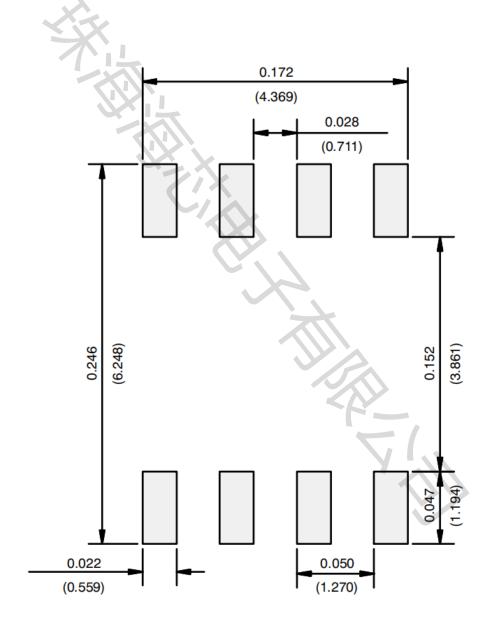




	MILLII	METERS		INCHES
DIM	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
<b>A</b> 1	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.007 5	0.010
D	4.80	5.00	0.189	0.196
Е	3.80	4.00	0.150	0.157
е	1	.27 BSC		0.050 BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026

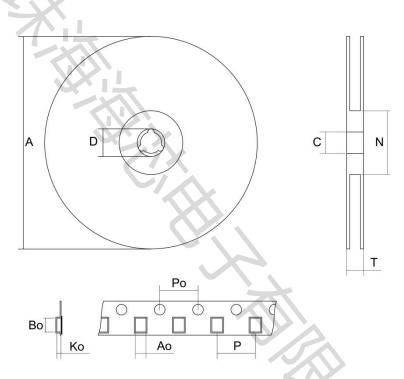
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### **RECOMMENDED MINIMUM PADS FOR SOP-8**

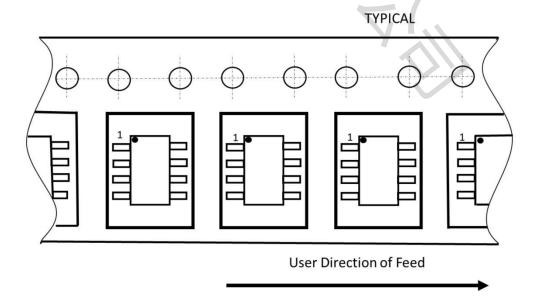


## **SOP-8** packing information

### SOP-8 tape and reel



### **Tape orientation**



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